

Cascadable Silicon Bipolar MMIC Amplifier

Technical Data

MSA-0786

Features

- Cascadable 50 Ω Gain Block
- Low Operating Voltage: 4.0 V Typical V_d
- 3 dB Bandwidth: DC to 2.0 GHz
- 12.5 dB Typical Gain at
 1.0 GHz
- Unconditionally Stable (k>1)
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available^[1]

Note:

 Refer to PACKAGING section "Tapeand-Reel Packaging for Semiconductor Devices."

Description

The MSA-0786 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose $50~\Omega$ gain block. Applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

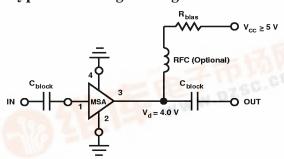
The MSA-series is fabricated using HP's 10 GHz f_T, 25 GHz f_{MAX}, silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metalli-

86 Plastic Package



zation to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

Typical Biasing Configuration





MSA-0786 Absolute Maximum Ratings

| Parameter | Absolute Maximum[1] | | | | |
|------------------------------------|---------------------|--|--|--|--|
| Device Current | 60 mA | | | | |
| Power Dissipation ^[2,3] | 275 mW | | | | |
| RF Input Power | +13 dBm | | | | |
| Junction Temperature | 150°C | | | | |
| Storage Temperature | −65 to 150°C | | | | |

| Thermal Resistance [2,4]: | |
|--|--|
| $\theta_{\rm jc} = 120^{\circ} \text{C/W}$ | |

Notes:

- 1. Permanent damage may occur if any of these limits are exceeded.
- 2. $T_{CASE} = 25$ °C.
- 3. Derate at 8.3 mW/°C for $T_C > 117$ °C.
- 4. See MEASUREMENTS section "Thermal Resistance" for more information.

Electrical Specifications^[1], $T_A = 25$ °C

| Symbol | Parameters and Test Conditions: | Units | Min. | Тур. | Max. | |
|-------------------------|--|------------------------------|-------|-------|--------------|-----|
| G _P | Power Gain $(S_{21} ^2)$ | f = 0.1 GHz f = 1.0 GHz | dB | 10.5 | 13.5 12.5 | |
| ΔG_{P} | Gain Flatness | f = 0.1 to 1.3 GHz | dB | | ±0.7 | |
| f3 dB | 3 dB Bandwidth | | GHz | | 2.0 | |
| VSWR | Input VSWR | f = 0.1 to 2.5 GHz | | | 1.7:1 | |
| VSWK | Output VSWR | | | 1.7:1 | | |
| NF | 50 Ω Noise Figure | f = 1.0 GHz | dB | | 5.0 | |
| P _{1 dB} | Output Power at 1 dB Gain Compression | f = 1.0 GHz | dBm | | 5.5 | |
| IP ₃ | Third Order Intercept Point | f = 1.0 GHz | dBm | | 19.0 | |
| t _D | Group Delay | f = 1.0 GHz | psec | | 150 | |
| V _d | Device Voltage | | V | 3.2 | 4.0 | 4.8 |
| dV/dT | Device Voltage Temperature Coefficient | | mV/°C | | -7.0 | |

Note:

Part Number Ordering Information

| Part Number | No. of Devices | Container | | |
|--------------|----------------|----------------|--|--|
| MSA-0786-TR1 | 1000 | 7" Reel | | |
| MSA-0786-BLK | 100 | Antistatic Bag | | |

For more information, see "Tape and Reel Packaging for Semiconductor Devices".

^{1.} The recommended operating current range for this device is 15 to 40 mA. Typical performance as a function of current is on the following page.

| MSA-0786 Typical Scattering | Parameters $(Z_0 =$ | 50 Ω , $T_{\Lambda} = 1$ | $25^{\circ}C$, $I_d = 22 \text{ mA}$) |
|-----------------------------|---|---------------------------------|---|
| · | • | / A | / u |

| Freq. | S ₁₁ | | S ₂₁ | | S ₁₂ | | | S ₂₂ | | |
|-------|-----------------|------|-----------------|------|-----------------|-------|------|-----------------|-----|------|
| GHz | Mag | Ang | dB | Mag | Ang | dB | Mag | Ang | Mag | Ang |
| 0.1 | .05 | 175 | 13.5 | 4.74 | 174 | -18.7 | .116 | 1 | .14 | -12 |
| 0.2 | .05 | 174 | 13.4 | 4.71 | 169 | -18.7 | .117 | 3 | .14 | -22 |
| 0.4 | .04 | 167 | 13.3 | 4.64 | 158 | -18.4 | .120 | 4 | .15 | -44 |
| 0.6 | .04 | 175 | 13.1 | 4.52 | 148 | -18.3 | .122 | 7 | .16 | -65 |
| 0.8 | .05 | -156 | 12.9 | 4.39 | 138 | -18.0 | .126 | 8 | .17 | -84 |
| 1.0 | .06 | -134 | 12.6 | 4.25 | 127 | -17.5 | .134 | 10 | .18 | -102 |
| 1.5 | .08 | -142 | 11.6 | 3.79 | 103 | -16.6 | .148 | 9 | .21 | -139 |
| 2.0 | .15 | -159 | 10.5 | 3.34 | 80 | -15.7 | .164 | 7 | .23 | -164 |
| 2.5 | .25 | -176 | 9.2 | 2.89 | 63 | -15.1 | .176 | 5 | .24 | 174 |
| 3.0 | .33 | 166 | 7.8 | 2.45 | 44 | -14.7 | .185 | 1 | .24 | 159 |
| 3.5 | .41 | 150 | 6.5 | 2.11 | 27 | -14.9 | .179 | -5 | .24 | 149 |
| 4.0 | .49 | 137 | 5.2 | 1.82 | 12 | -15.1 | .177 | _9 | .23 | 145 |
| 5.0 | .60 | 116 | 3.0 | 1.41 | -14 | -15.4 | .169 | -14 | .26 | 145 |

Note:

1. A model for this device is available in the DEVICE MODELS section.

Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

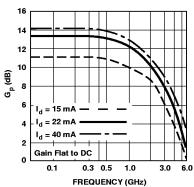


Figure 1. Typical Power Gain vs. Frequency.

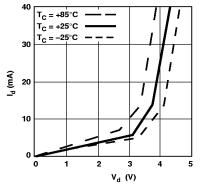


Figure 2. Device Current vs. Voltage.

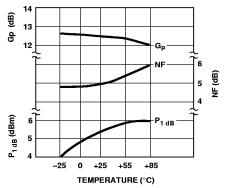


Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, f = 1.0 GHz, I_d = 22 mA.

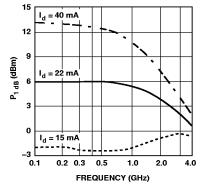


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

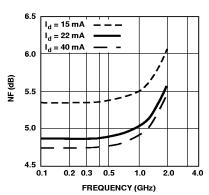
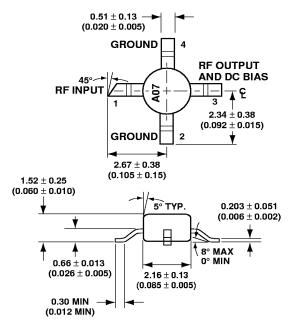


Figure 5. Noise Figure vs. Frequency.



86 Plastic Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES)

www.hp.com/go/rf

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Obsoletes 5965-9594E

5968-4716E (3/99)